

Product data sheet

1. General description

Planar passivated ultra sensitive gate Silicon Controlled Rectifier in a TO92 plastic package.

2. Features and benefits

- Planar passivated for voltage ruggedness and reliability
- Ultra sensitive gate

3. Applications

- Electronic ballasts
- · Safety shut down and protection circuits
- Sensing circuits
- Smoke detectors
- Switched Mode Power Supplies

4. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Absolute	maximum rating					
V_{DRM}	repetitive peak offstate voltage		-	-	400	V
V_{RRM}	repetitive peak reverse voltage		-	-	400	V
I _{T(AV)}	average on-state current	half sine wave; T _{lead} ≤ 92 °C; <u>Fig. 1</u>	-	-	0.5	A
I _{T(RMS)}	RMS on-state current	half sine wave; T _{lead} ≤ 92 °C; <u>Fig. 2;</u> <u>Fig. 3</u>	-	-	0.8	А
I _{TSM}	non-repetitive peak on- state current	half sine wave; $T_{j(init)}$ = 25 °C; t_p = 10 ms; Fig. 4; Fig. 5	-	-	8	А
Static cha	racteristics					
I _{GT}	gate trigger current	V _D = 12 V; I _T = 10 mA; T _i = 25 °C; <u>Fig. 7</u>	-	3	12	μA

5. Pinning information

Table 2. F	Table 2. Pinning information								
Pin	Symbol	Description	Simplified outline	Graphic symbol					
1	A	anode							
2	G	gate	L, , , , , , , , , , , , , , , , , , ,	А Ң К					
3	К	cathode	() (G sym037					

6. Ordering information

Table 3. Ordering information							
Type number	Package Name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date	
EC103D1	TO92	EC103D1,412	Bulk	1000	SOT54	14-Nov-2013	
EC103D1	TO92	EC103D1,116	Reel	2000	SOT54 wide pitch	14-Nov-2013	

7. Marking

Table 4. Marking codes							
	Type number	Marking codes					
	EC103D1	EC103D1					

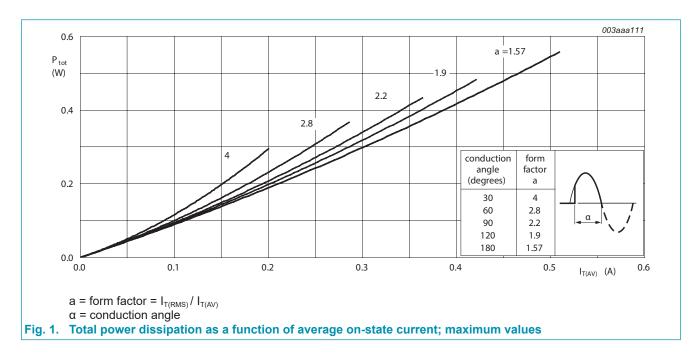
8. Limiting values

Table 5. Limiting values

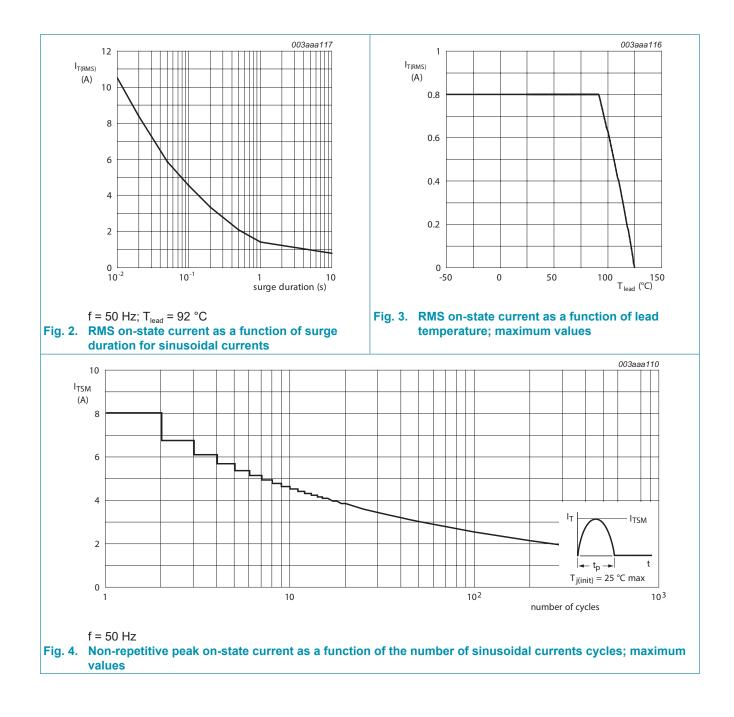
In accordance with the Absolute Maximum Rating System (IEC 60134).

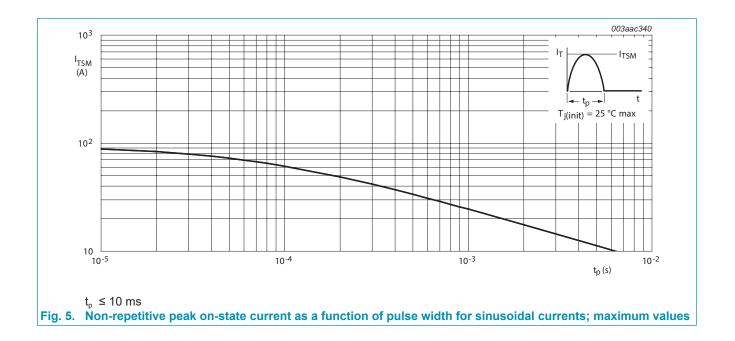
Symbol	Parameter	Conditions		Min	Max	Unit
V _{DRM}	repetitive peak off-state voltage			-	400	V
V_{RRM}	repetitive peak reverse voltage			-	400	V
$I_{T(AV)}$	average on-state current	half sine wave; T _{lead} ≤ 92 °C; <u>Fig. 1</u>		-	0.5	А
I _{T(RMS)}	RMS on-state current	half sine wave; T _{lead} ≤ 92 °C; <u>Fig. 2</u> ; <u>Fig. 3</u>		-	0.8	А
I _{TSM}	non-repetitive peak on- state current	half sine wave; $T_{j(init)}$ = 25 °C; t_p = 10 ms; Fig. 4; Fig. 5		-	8	A
		half sine wave; $T_{j(init)}$ = 25 °C; t_p = 8.3 ms		-	9	А
l ² t	l ² t for fusing	t _p = 10 ms; SIN		-	0.32	A ² s
dl _⊤ /dt	rate of rise of on-state current	$I_T = 2 \text{ A}; I_G = 10 \text{ mA}; \text{ d}I_G/\text{d}t = 100 \text{ mA}/\mu\text{s}$		-	50	A/µs
I _{GM}	peak gate current			-	1	А
V _{RGM}	peak reverse gate voltage			-	5	V
P _{GM}	peak gate power			-	2	W
P _{G(AV)}	average gate power	over any 20 ms period		-	0.1	W
T _{stg}	storage temperature			-40	150	°C
T _i	junction temperature		[1]	-	125	°C

[1] Operation above 110°C may require the use of a gate to cathode resistor of $1k\Omega$ or less.



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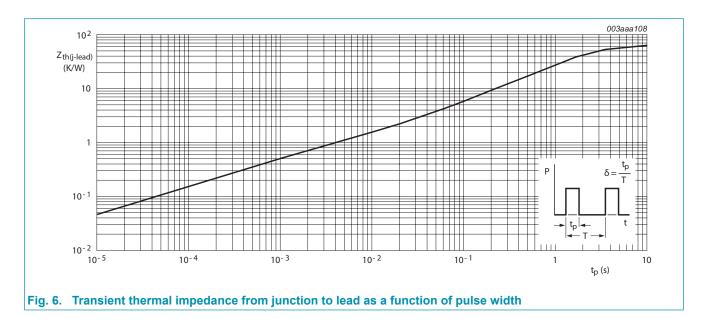


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9. Thermal characteristics

Table 6. Th	ermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{\text{th(j-lead)}}$	thermal resistance from junction to lead	<u>Fig. 6</u>	-	-	60	K/W
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient free air	printed circuit board mounted: lead length = 4 mm	-	150	-	K/W

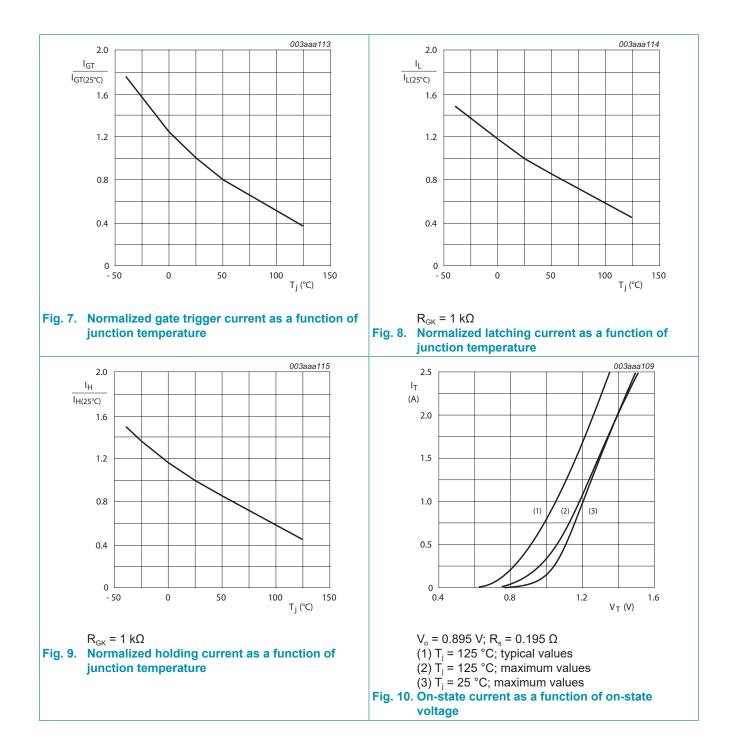


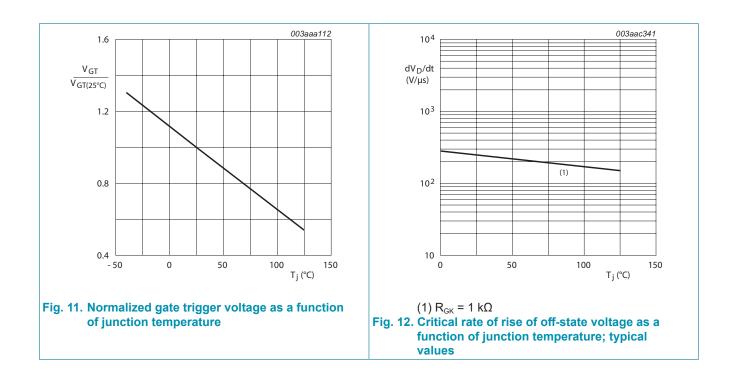
10. Characteristics

	haracteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	aracteristics					
I _{GT}	gate trigger current	V _D = 12 V; I _T = 10 mA; T _j = 25 °C; <u>Fig. 7</u>	-	3	12	μA
I _L	latching current	V_D = 12 V; I _G = 0.5 mA; R _{GK} = 1 kΩ; T _j = 25 °C; Fig. 8	-	2	6	mA
I _H	holding current	V_{D} = 12 V; R _{GK} = 1 kΩ; T _j = 25 °C; Fig. 9	-	2	5	mA
V _T	on-state voltage	I _T = 1 A; T _j = 25 °C; <u>Fig. 10</u>	-	1.2	1.35	V
V _{GT}	gate trigger voltage	$V_{D} = 12 \text{ V}; \text{ I}_{T} = 10 \text{ mA}; \text{ T}_{J} = 25 \text{ °C};$ Fig. 11	-	0.5	0.8	V
		V _D = 400 V; I _T = 10 mA; T _j = 125 °C	0.2	0.3	-	V
I _D	off-state current	$V_{\rm D}$ = 400 V; $R_{\rm GK}$ = 1 kΩ; $T_{\rm j}$ = 125 °C	-	0.05	0.1	mA
I _R	reverse current	$V_{\rm D}$ = 400 V; $R_{\rm GK}$ = 1 kΩ; $T_{\rm j}$ = 125 °C	-	0.05	0.1	mA
Dynamic	characteristics					
dV _D /dt	rate of rise of off-state voltage		-	150	-	V/µs
t _{gt}	gate-controlled turn-on time	$I_{TM} = 2 \text{ A}; V_D = 400 \text{ V}; I_G = 10 \text{ mA}; \text{ d}I_G/$ dt = 0.1 A/µs; T _j = 25 °C	-	2	-	μs
t _q	commutated turn-off time		-	100	-	μs

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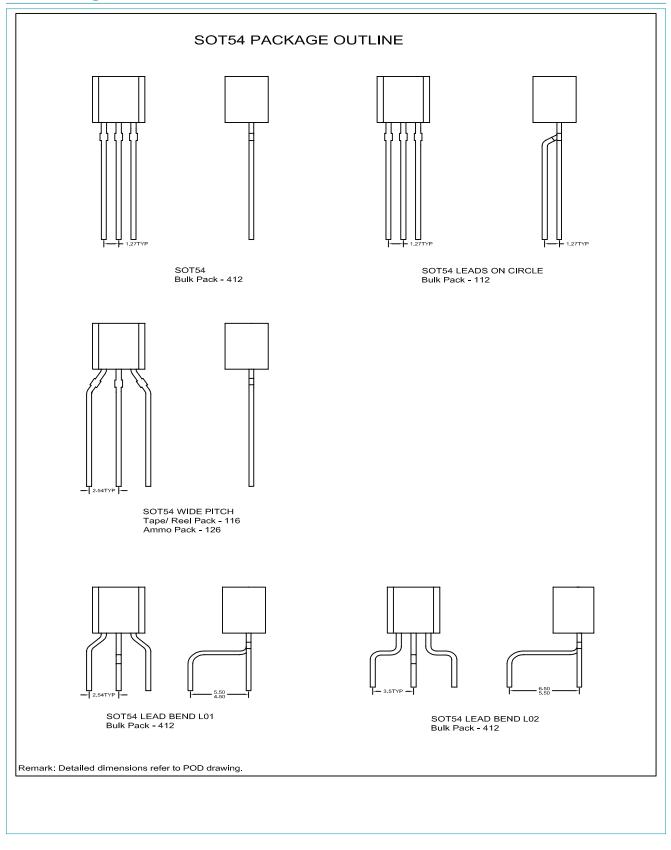


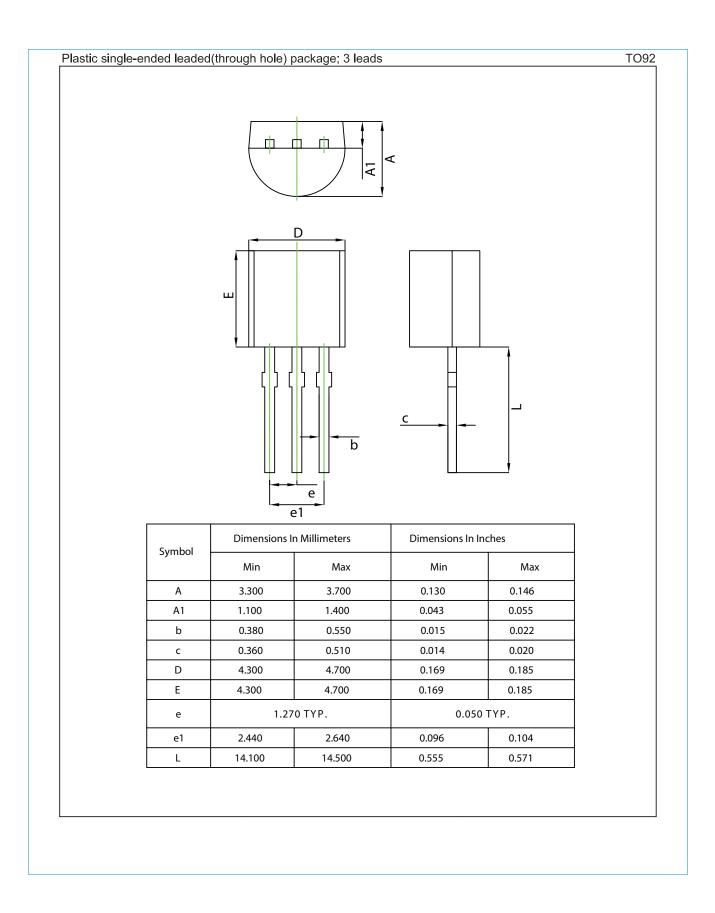


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11. Package outline





12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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